16 V, 1 MHz, CMOS Rail-to-Rail Input/Output Operational Amplifier

ADA4665-2

FEATURES

Lower power at high voltage: 290 µA per amplifier typical
Low input bias current: 1 pA maximum
Wide bandwidth: 1.2 MHz typical
Slew rate: 1 V/µs typical
Offset voltage drift: 3 µV/°C typical
Single-supply operation: 5 V to 16 V
Dual-supply operation: ±2.5 V to ±8 V
Unity gain stable

APPLICATIONS

Portable systems
High density power budget systems
Medical equipment
Physiological measurement
Precision references
Multipole filters
Sensors
Transimpedance amplifiers
Buffer/level shifting

GENERAL DESCRIPTION

The ADA4665-2 is a rail-to-rail input/output dual amplifier optimized for lower power budget designs. The ADA4665-2 offers a low supply current of 400 µA maximum per amplifier at 25°C and 600 µA maximum per amplifier over the extended industrial temperature range. This feature makes the ADA4665-2 well suited for low power applications. In addition, the ADA4665-2 has a very low bias current of 1 pA maximum, low offset voltage drift of 3 µV/°C, and bandwidth of 1.2 MHz. The combination of these features, together with a wide supply voltage range from 5 V to 16 V, allows the device to be used in a wide variety of other applications, including process control, instrumentation equipment, buffering, and sensor front ends. Furthermore, its rail-to-rail input and output swing adds to its versatility. The ADA4665-2 is specified from −40°C to +125°C and is available in standard SOIC and MSOP packages.

PIN CONFIGURATIONS

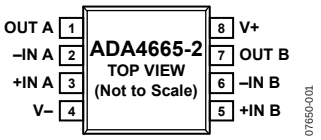

Figure 1. 8-Lead SOIC

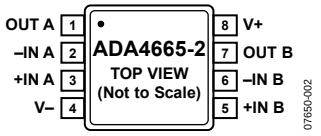

Figure 2. 8-Lead MSOP

Table 1. Low Cost Rail-to-Rail Input/Output Op Amps

Supply	5 V	16 V
Single	AD8541	
Dual	AD8542	ADA4665-2
Quad	AD8544	

Table 2. Other Rail-to-Rail Input/Output Op Amps

Supply	5 V	16 V	36 V
Single	AD8603	AD8663	
Dual	AD8607	AD8667	ADA4091-2
Quad	AD8609	AD8669	

Rev. 0

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REVISION HISTORY

1/09—Revision 0: Initial Version

SPECIFICATIONS

ELECTRICAL CHARACTERISTICS—16 V OPERATION

V_{SY} = 16 V, V_{CM} = V_{SY}/2, T_A = 25°C, unless otherwise noted.

Table 3.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	V_{CM} = 16 V		1	4	mV
		V_{CM} = 0 V to 16 V		1	6	mV
		−40°C ≤ T_A ≤ +125°C			9	mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	−40°C ≤ T_A ≤ +125°C		3		µV/°C
Input Bias Current	I_B			0.1	1	pA
		−40°C ≤ T_A ≤ +125°C			200	pA
Input Offset Current	I_{OS}			0.1	1	pA
		−40°C ≤ T_A ≤ +125°C			40	pA
Input Voltage Range		−40°C ≤ T_A ≤ +125°C	0		16	V
Common-Mode Rejection Ratio	CMRR	V_{CM} = 0 V to 16 V	55	75		dB
		−40°C ≤ T_A ≤ +125°C	50			dB
Large Signal Voltage Gain	A_{VO}	R_L = 10 kΩ, V_O = 0.5 V to 15 V	85	100		dB
		−40°C ≤ T_A ≤ +125°C	75			dB
Input Resistance	R_{IN}			4		GΩ
Input Capacitance, Differential Mode	C_{INDM}			2		pF
Input Capacitance, Common Mode	C_{INCM}			7		pF
OUTPUT CHARACTERISTICS						
Output Voltage High	V_{OH}	R_L = 100 kΩ to V_{CM}	15.95	15.99		V
		−40°C ≤ T_A ≤ +125°C	15.9			V
		R_L = 10 kΩ to V_{CM}	15.9	15.95		V
		−40°C ≤ T_A ≤ +125°C	15.8			V
Output Voltage Low	V_{OL}	R_L = 100 kΩ to V_{CM}		4	7.5	mV
		−40°C ≤ T_A ≤ +125°C			15	mV
		R_L = 10 kΩ to V_{CM}		40	75	mV
		−40°C ≤ T_A ≤ +125°C			150	mV
Short-Circuit Current	I_{SC}			±30		mA
Closed-Loop Output Impedance	Z_{OUT}	f = 100 kHz, A_V = 1		100		Ω
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	V_{SY} = 5 V to 16 V	70	95		dB
		−40°C ≤ T_A ≤ +125°C	65			dB
Supply Current per Amplifier	I_{SY}	I_O = 0 mA		290	400	µA
		−40°C ≤ T_A ≤ +125°C			600	µA
DYNAMIC PERFORMANCE						
Slew Rate	SR	R_L = 10 kΩ, C_L = 50 pF, A_V = 1		1		V/µs
Settling Time to 0.1%	t_S	V_{IN} = 1 V step, R_L = 2 kΩ, C_L = 50 pF		6.5		µs
Gain Bandwidth Product	GBP	R_L = 10 kΩ, C_L = 50 pF, A_V = 1		1.2		MHz
Phase Margin	Φ_M	R_L = 10 kΩ, C_L = 50 pF, A_V = 1		50		Degrees
NOISE PERFORMANCE						
Voltage Noise	e_n p-p	f = 0.1 Hz to 10 Hz		3		µV p-p
Voltage Noise Density	e_n	f = 1 kHz		32		nV/√Hz
		f = 10 kHz		27		nV/√Hz
Current Noise Density	i_n	f = 1 kHz		50		fA/√Hz

ELECTRICAL CHARACTERISTICS—5 V OPERATION

V_{SY} = 5 V, V_{CM} = V_{SY}/2, T_A = 25°C, unless otherwise noted.

Table 4.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	V_{CM} = 5 V		1	4	mV
		V_{CM} = 0 V to 5 V		1	6	mV
		−40°C ≤ T_A ≤ +125°C			9	mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	−40°C ≤ T_A ≤ +125°C		3		µV/°C
Input Bias Current	I_B			0.1	1	pA
		−40°C ≤ T_A ≤ +125°C			100	pA
Input Offset Current	I_{OS}			0.1	1	pA
		−40°C ≤ T_A ≤ +125°C			10	pA
Input Voltage Range		−40°C ≤ T_A ≤ +125°C	0		5	V
Common-Mode Rejection Ratio	CMRR	V_{CM} = 0 V to 5 V	55	75		dB
		−40°C ≤ T_A ≤ +125°C	50			dB
Large Signal Voltage Gain	A_{VO}	R_L = 10 kΩ, V_O = 0.5 V to 4.5 V	85	100		dB
		−40°C ≤ T_A ≤ +125°C	75			dB
Input Resistance	R_{IN}			1		GΩ
Input Capacitance, Differential Mode	C_{INDM}			2		pF
Input Capacitance, Common Mode	C_{INCM}			7		pF
OUTPUT CHARACTERISTICS						
Output Voltage High	V_{OH}	R_L = 100 kΩ to V_{CM}	4.95	4.99		V
		−40°C ≤ T_A ≤ +125°C	4.9			V
		R_L = 10 kΩ to V_{CM}	4.9	4.96		V
		−40°C ≤ T_A ≤ +125°C	4.8			V
Output Voltage Low	V_{OL}	R_L = 100 kΩ to V_{CM}		3	5	mV
		−40°C ≤ T_A ≤ +125°C			10	mV
		R_L = 10 kΩ to V_{CM}		30	50	mV
		−40°C ≤ T_A ≤ +125°C			100	mV
Short-Circuit Current	I_{SC}			±8		mA
Closed-Loop Output Impedance	Z_{OUT}	f = 100 kHz, A_V = 1		100		Ω
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	V_{SY} = 5 V to 16 V	70	95		dB
		−40°C ≤ T_A ≤ +125°C	65			dB
Supply Current per Amplifier	I_{SY}	I_O = 0 mA		270	350	µA
		−40°C ≤ T_A ≤ +125°C			600	µA
DYNAMIC PERFORMANCE						
Slew Rate	SR	R_L = 10 kΩ, C_L = 50 pF, A_V = 1		1		V/µs
Settling Time to 0.1%	t_S	V_{IN} = 1 V step, R_L = 2 kΩ, C_L = 50 pF		6.5		µs
Gain Bandwidth Product	GBP	R_L = 10 kΩ, C_L = 50 pF, A_V = 1		1.2		MHz
Phase Margin	Φ_M	R_L = 10 kΩ, C_L = 50 pF, A_V = 1		50		Degrees
NOISE PERFORMANCE						
Voltage Noise	e_n p-p	f = 0.1 Hz to 10 Hz		3		µV p-p
Voltage Noise Density	e_n	f = 1 kHz		32		nV/√Hz
		f = 10 kHz		27		nV/√Hz
Current Noise Density	i_n	f = 1 kHz		50		fA/√Hz

ABSOLUTE MAXIMUM RATINGS

Table 5.

Parameter	Rating
Supply Voltage	16.5 V
Input Voltage[1]	GND − 0.3 V to V_{SY} + 0.3 V
Input Current	±10 mA
Differential Input Voltage	±V_{SY}
Output Short-Circuit Duration to GND	Indefinite
Storage Temperature Range	−65°C to +150°C
Operating Temperature Range	−40°C to +125°C
Junction Temperature Range	−65°C to +150°C
Lead Temperature (Soldering, 60 sec)	300°C

[1] The input pins have clamp diodes to the power supply pins.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages. This value was measured using a 4-layer JEDEC standard printed circuit board.

Table 6. Thermal Resistance

Package Type	θ_{JA}	θ_{JC}	Unit
8-Lead SOIC_N (R-8)	158	43	°C/W
8-Lead MSOP (RM-8)	186	52	°C/W

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

T_A = 25°C, unless otherwise noted.

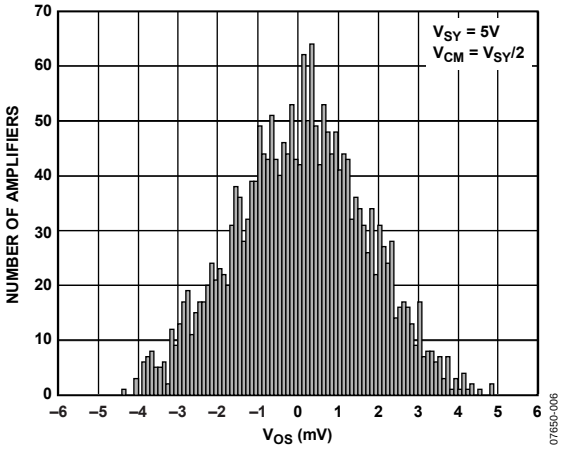

Figure 3. Input Offset Voltage Distribution

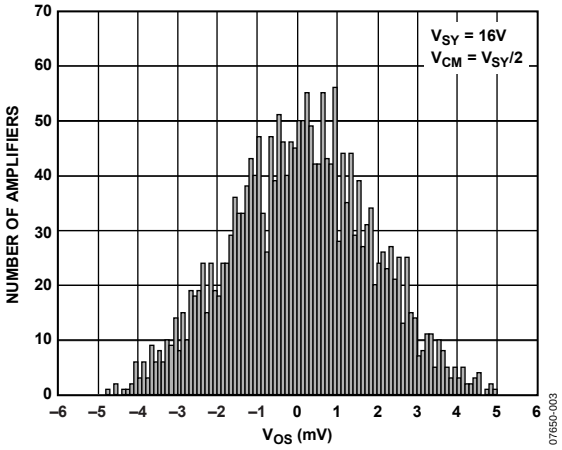

Figure 6. Input Offset Voltage Distribution

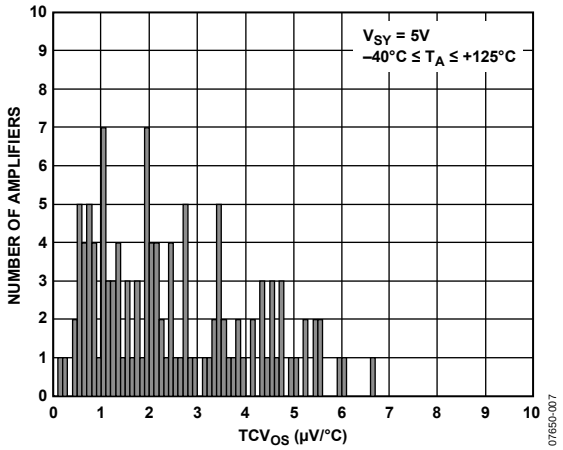

Figure 4. Input Offset Voltage Drift Distribution

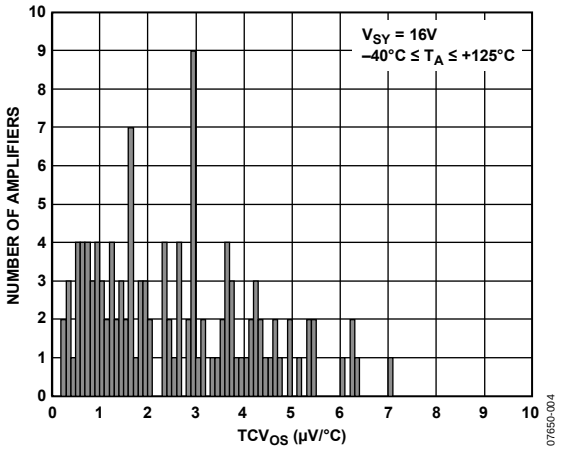

Figure 7. Input Offset Voltage Drift Distribution

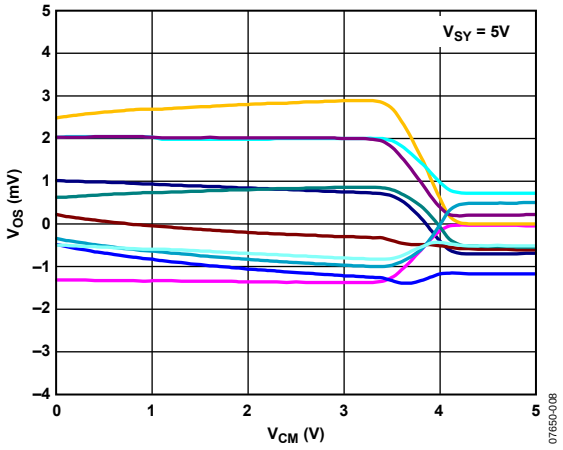

Figure 5. Input Offset Voltage vs. Common-Mode Voltage

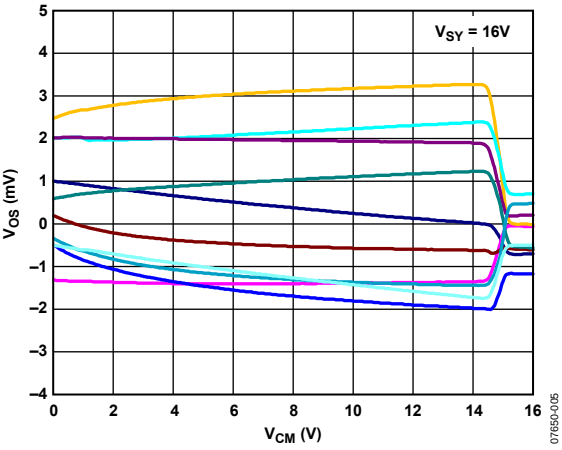

Figure 8. Input Offset Voltage vs. Common-Mode Voltage

T_A = 25°C, unless otherwise noted.

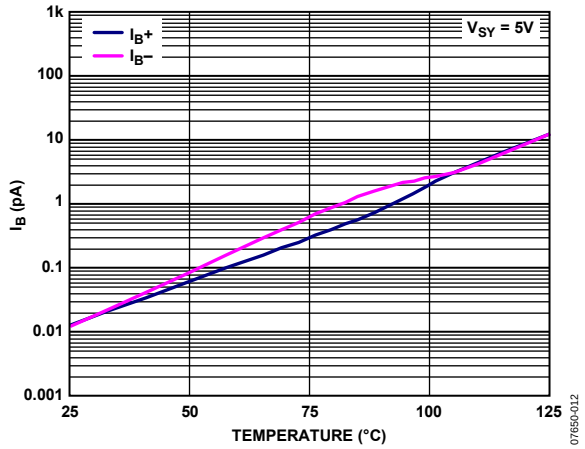

Figure 9. Input Bias Current vs. Temperature

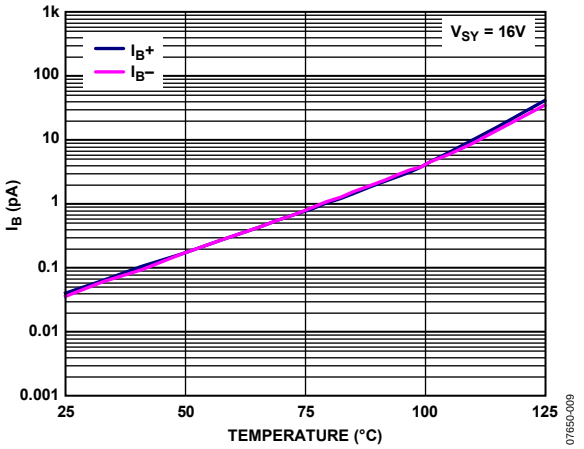

Figure 12. Input Bias Current vs. Temperature

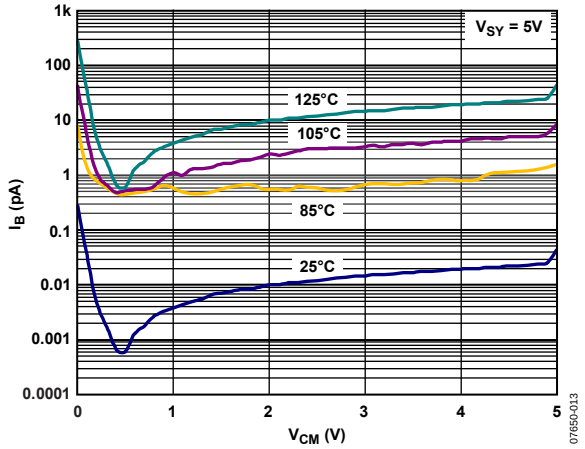

Figure 10. Input Bias Current vs. Input Common-Mode Voltage

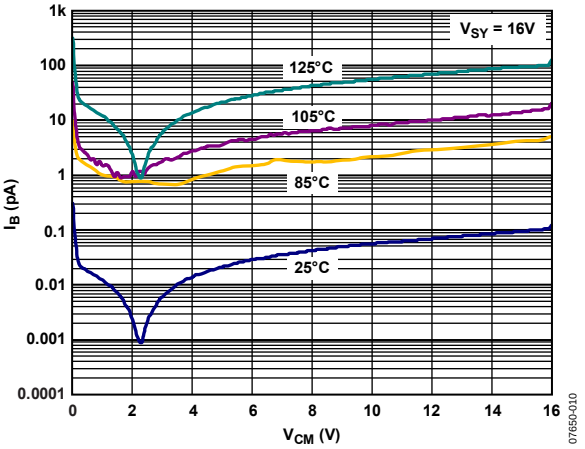

Figure 13. Input Bias Current vs. Input Common-Mode Voltage

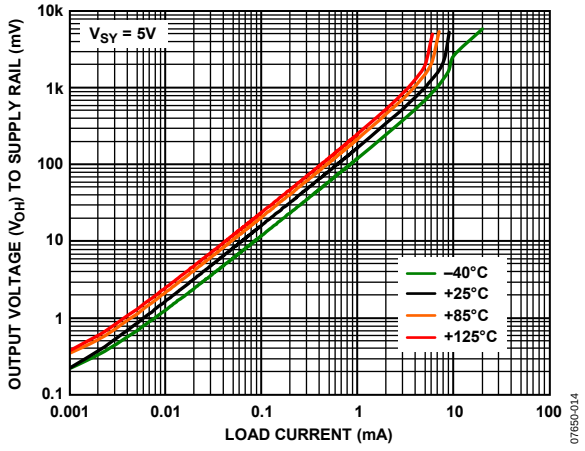

Figure 11. Output Voltage (V_{OH}) to Supply Rail vs. Load Current

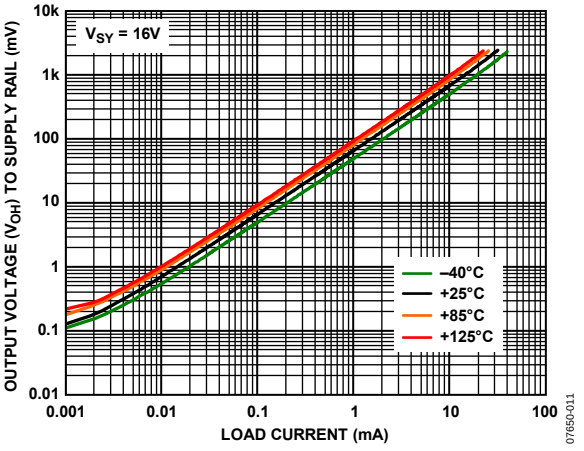

Figure 14. Output Voltage (V_{OH}) to Supply Rail vs. Load Current

T_A = 25°C, unless otherwise noted.

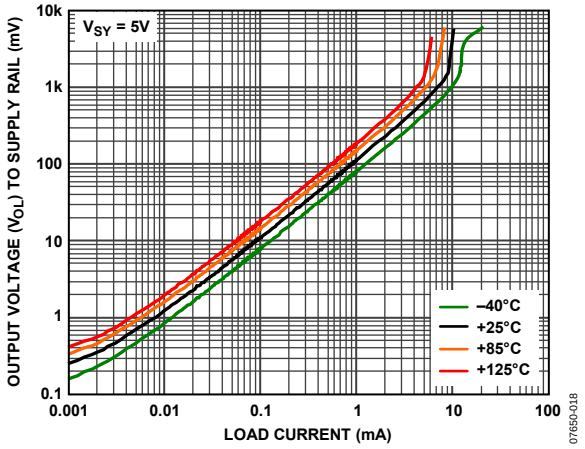

Figure 15. Output Voltage (V_{OL}) to Supply Rail vs. Load Current

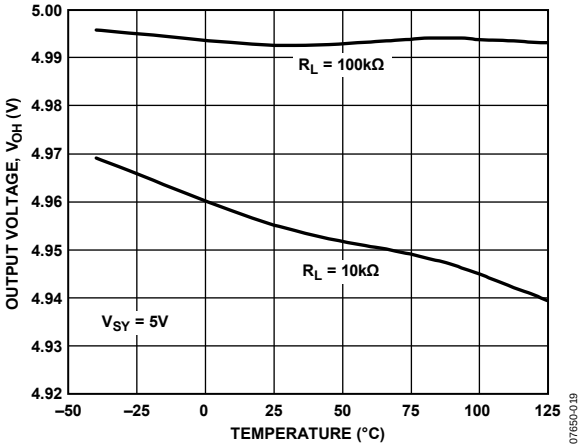

Figure 16. Output Voltage (V_{OH}) vs. Temperature

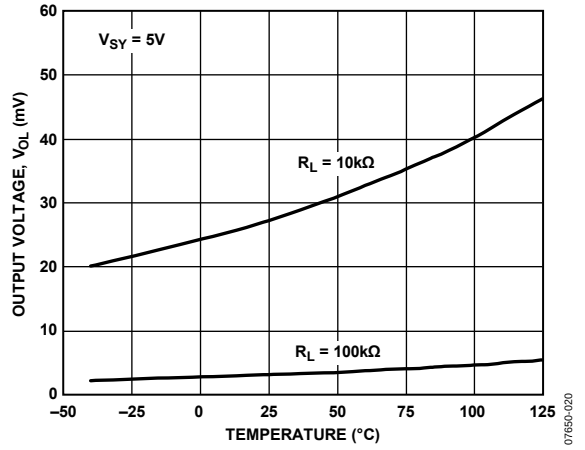

Figure 17. Output Voltage (V_{OL}) vs. Temperature

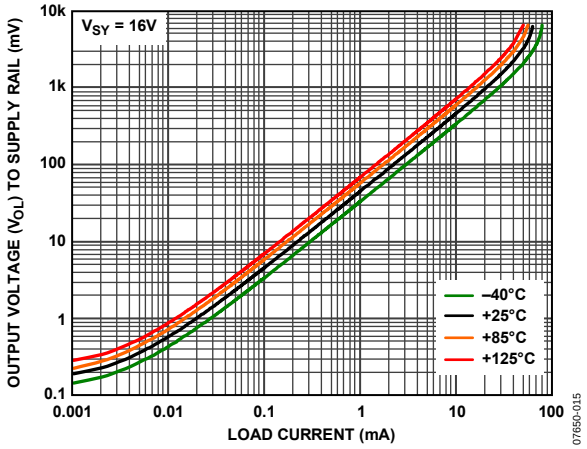

Figure 18. Output Voltage (V_{OL}) to Supply Rail vs. Load Current

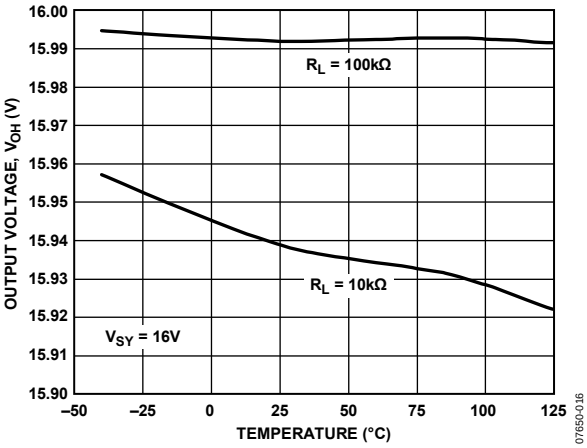

Figure 19. Output Voltage (V_{OH}) vs. Temperature

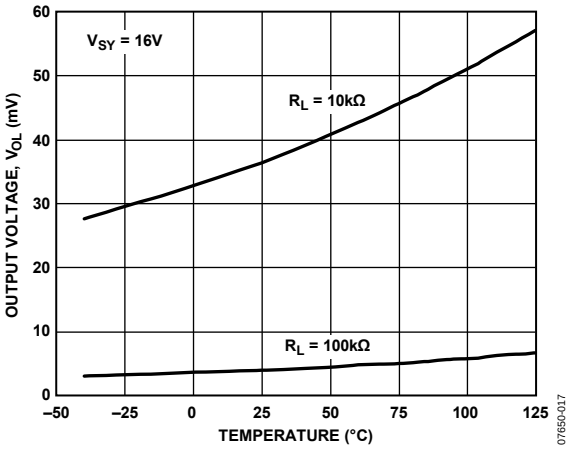

Figure 20. Output Voltage (V_{OL}) vs. Temperature

T_A = 25°C, unless otherwise noted.

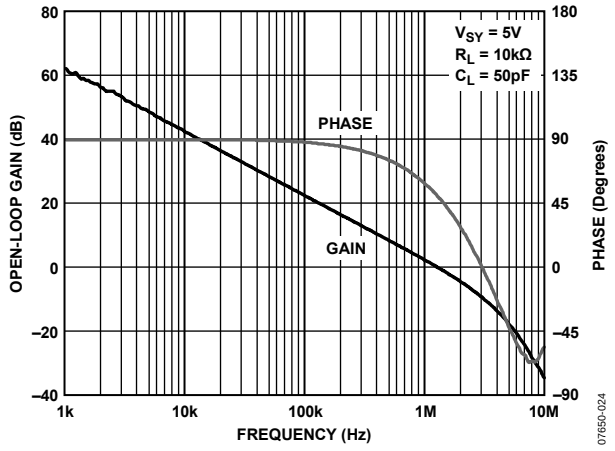

Figure 21. Open-Loop Gain and Phase vs. Frequency

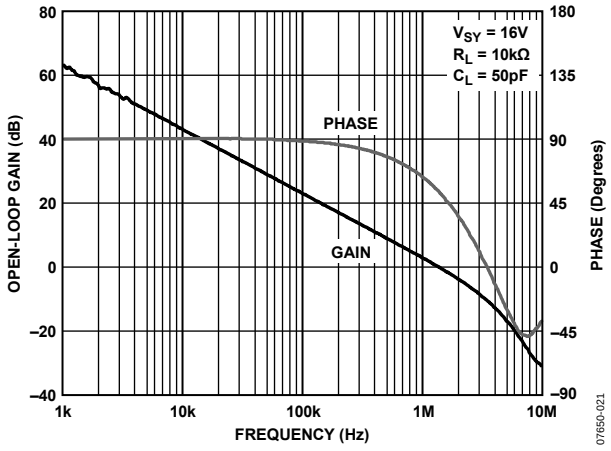

Figure 24. Open-Loop Gain and Phase vs. Frequency

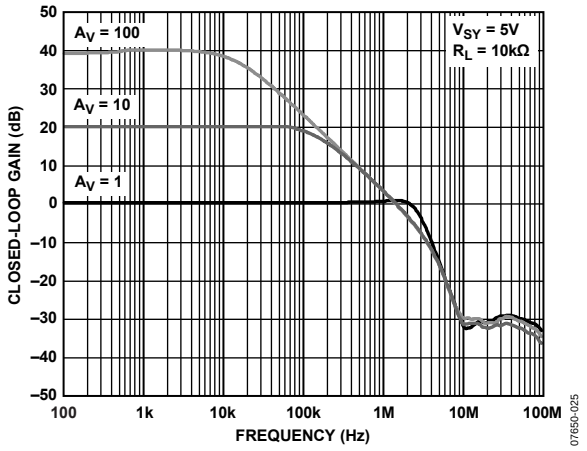

Figure 22. Closed-Loop Gain vs. Frequency

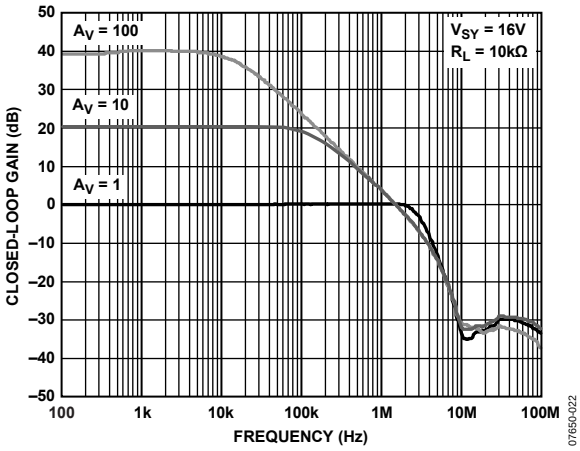

Figure 25. Closed-Loop Gain vs. Frequency

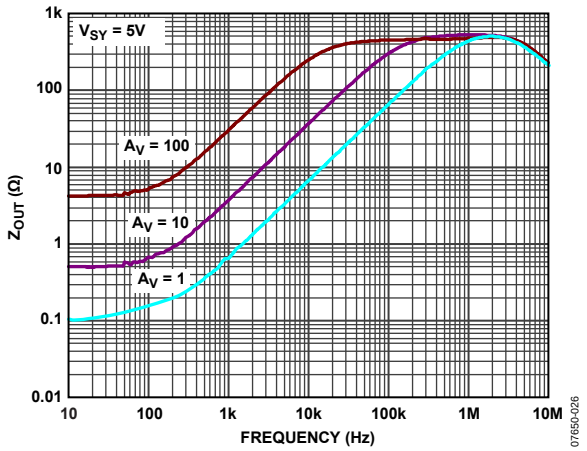

Figure 23. Output Impedance vs. Frequency

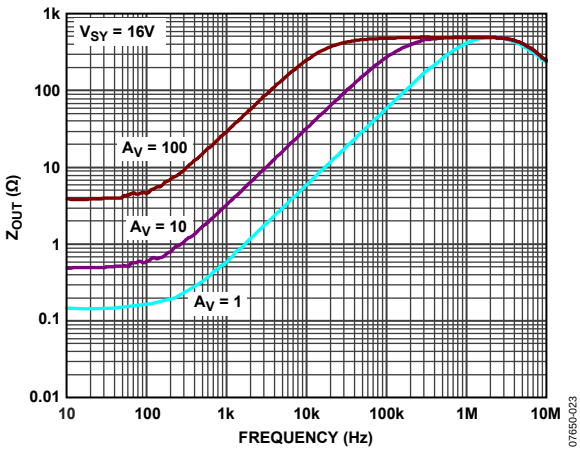

Figure 26. Output Impedance vs. Frequency

T_A = 25°C, unless otherwise noted.

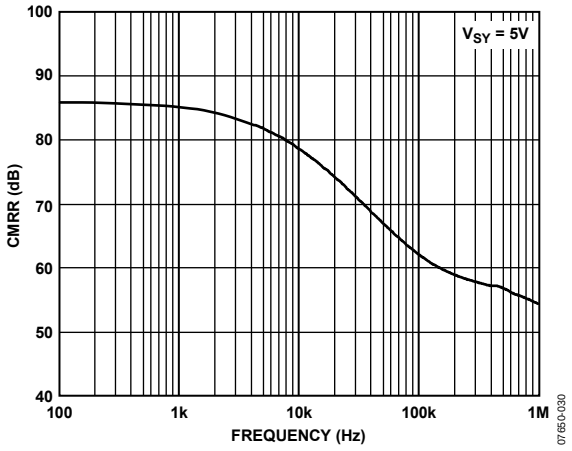

Figure 27. CMRR vs. Frequency

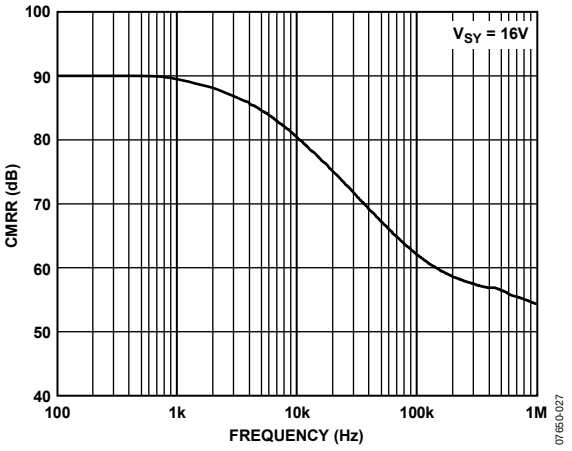

Figure 30. CMRR vs. Frequency

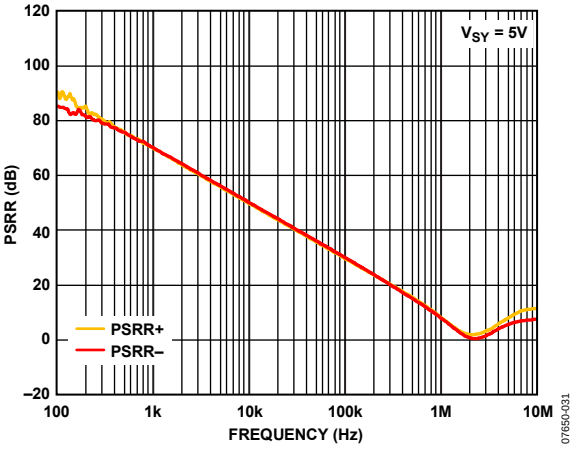

Figure 28. PSRR vs. Frequency

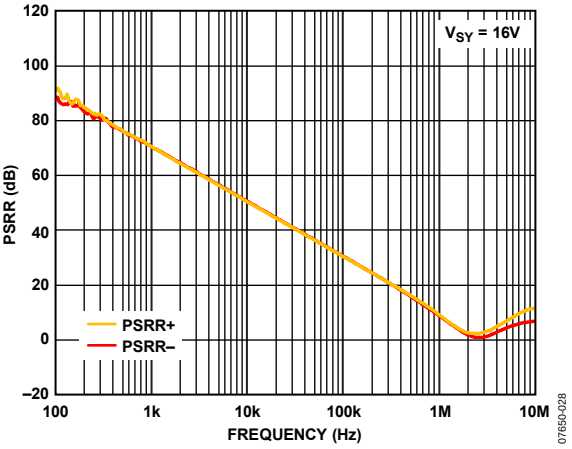

Figure 31. PSRR vs. Frequency

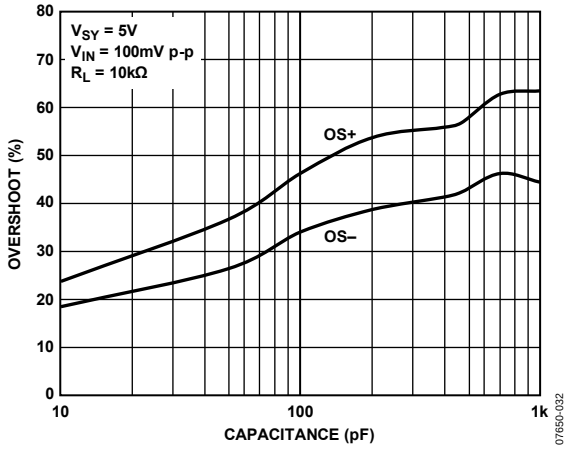

Figure 29. Small Signal Overshoot vs. Load Capacitance

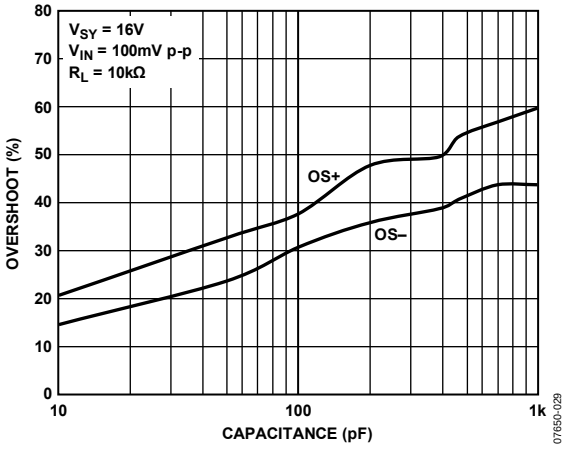

Figure 32. Small Signal Overshoot vs. Load Capacitance

T_A = 25°C, unless otherwise noted.

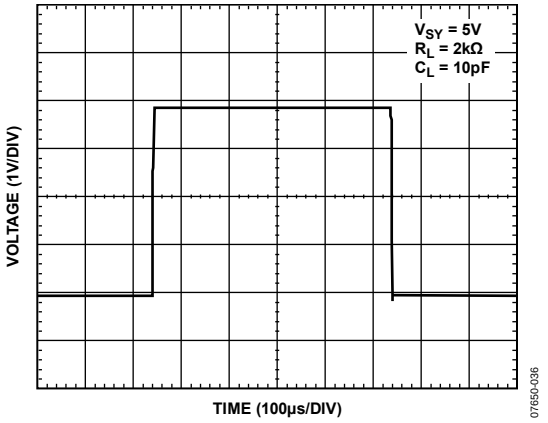

Figure 33. Large Signal Transient Response

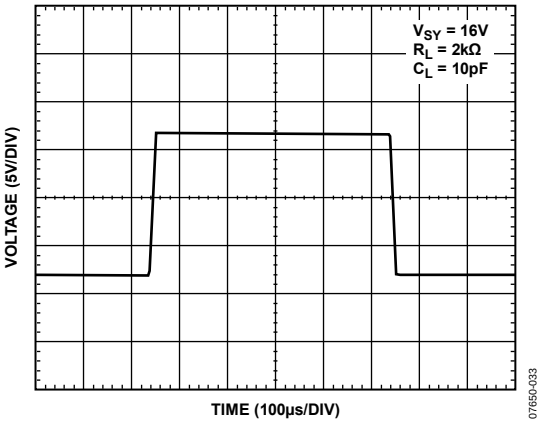

Figure 36. Large Signal Transient Response

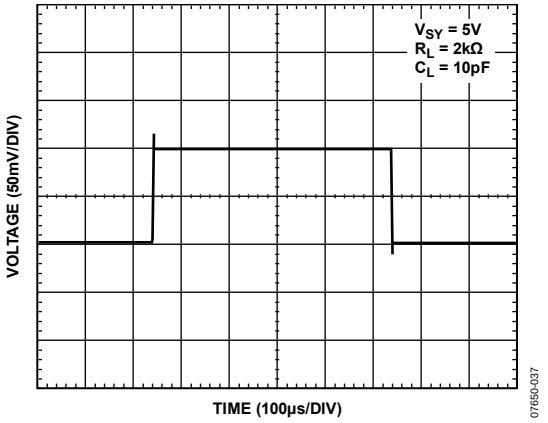

Figure 34. Small Signal Transient Response

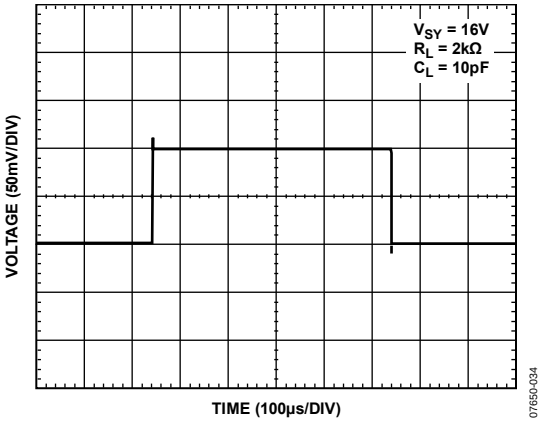

Figure 37. Small Signal Transient Response

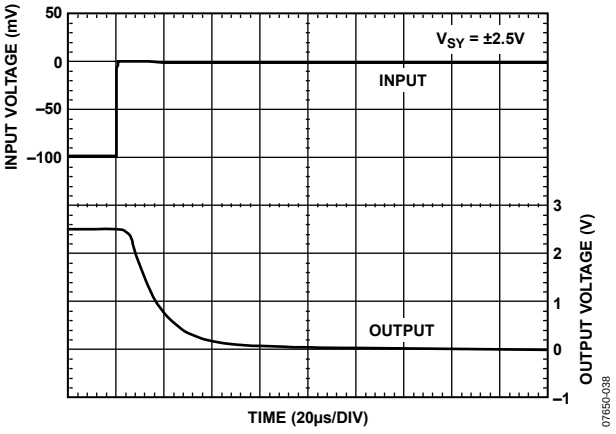

Figure 35. Positive Overload Recovery

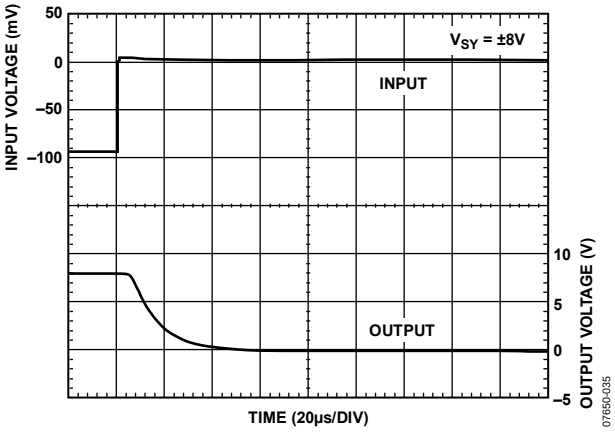

Figure 38. Positive Overload Recovery

T_A = 25°C, unless otherwise noted.

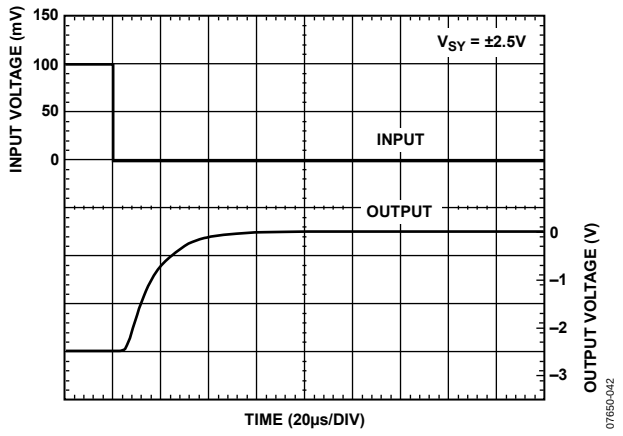

Figure 39. Negative Overload Recovery

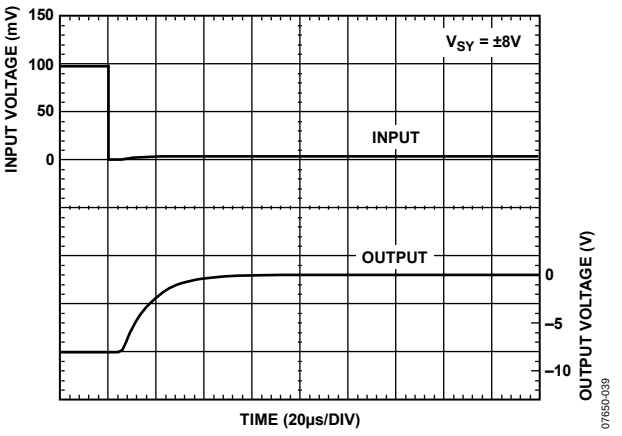

Figure 42. Negative Overload Recovery

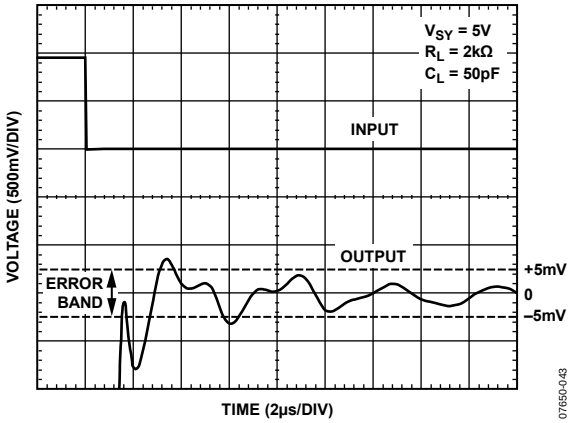

Figure 40. Negative Settling Time to 0.1%

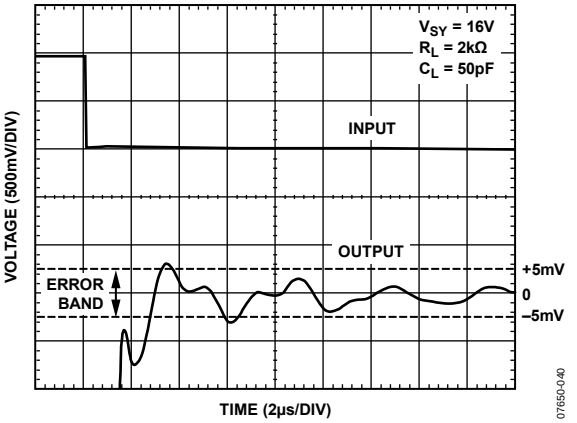

Figure 43. Negative Settling Time to 0.1%

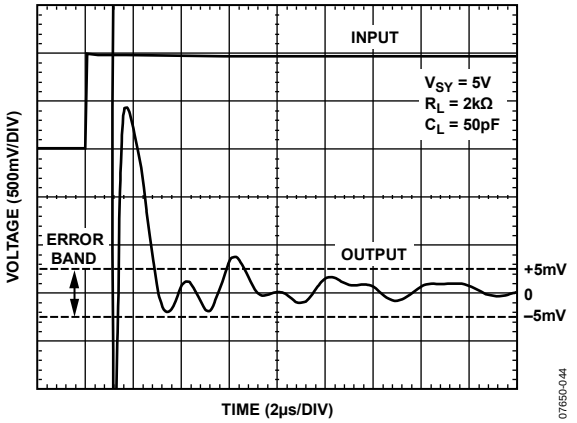

Figure 41. Positive Settling Time to 0.1%

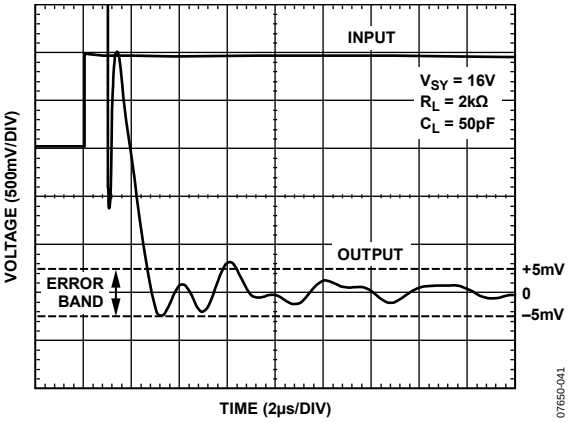

Figure 44. Positive Settling Time to 0.1%

T_A = 25°C, unless otherwise noted.

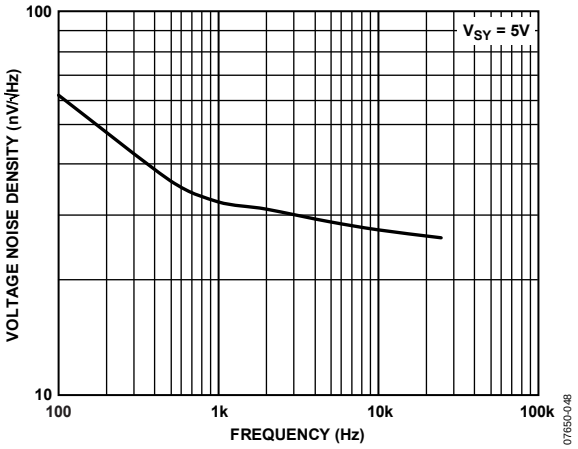

Figure 45. Voltage Noise Density vs. Frequency

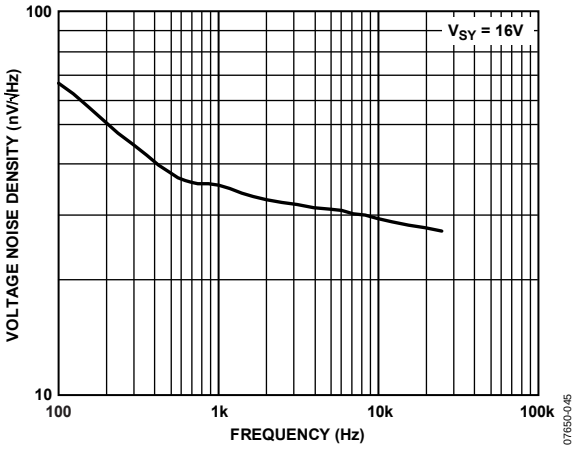

Figure 48. Voltage Noise Density vs. Frequency

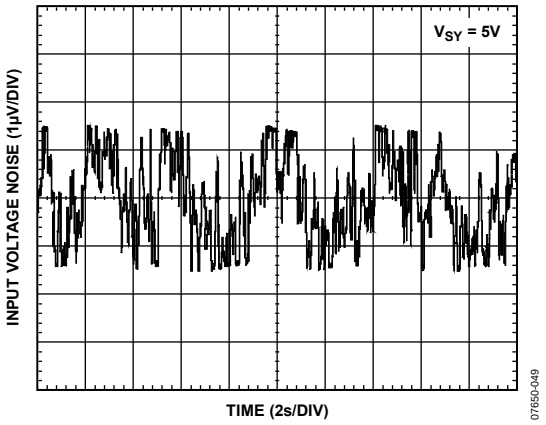

Figure 46. 0.1 Hz to 10 Hz Noise

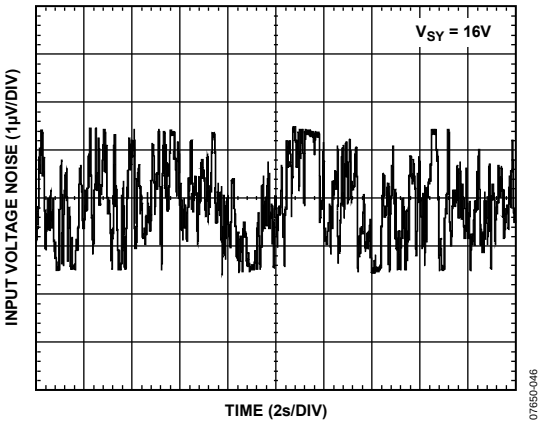

Figure 49. 0.1 Hz to 10 Hz Noise

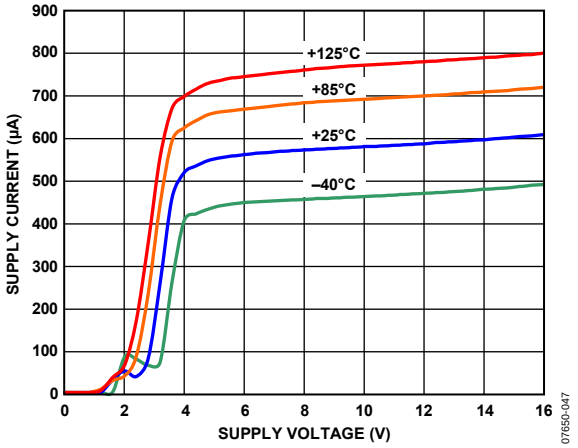

Figure 47. Supply Current vs. Supply Voltage

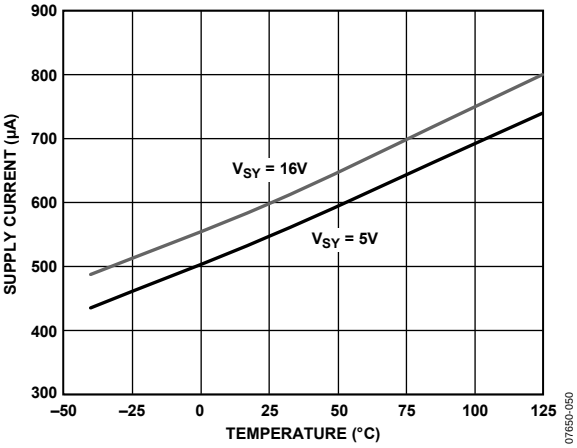

Figure 50. Supply Current vs. Temperature

T_A = 25°C, unless otherwise noted.

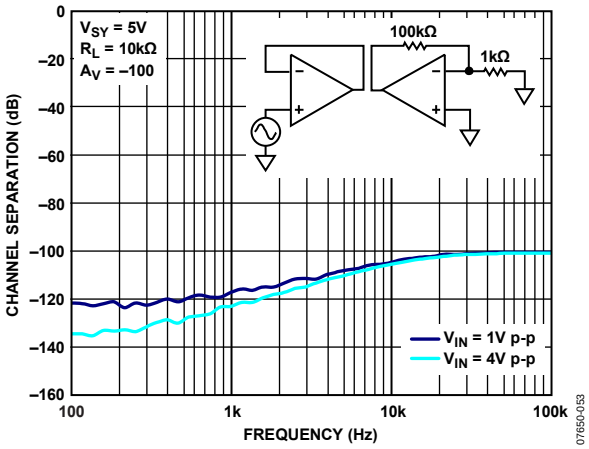

Figure 51. Channel Separation vs. Frequency

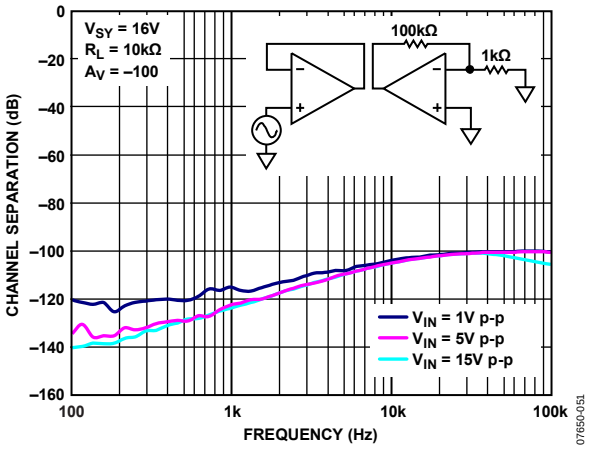

Figure 53. Channel Separation vs. Frequency

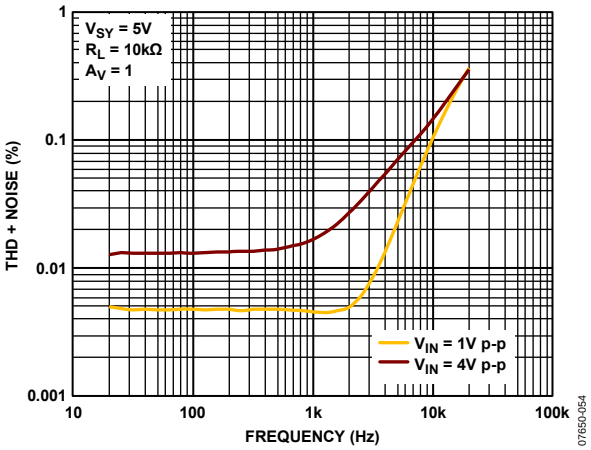

Figure 52. THD + Noise vs. Frequency

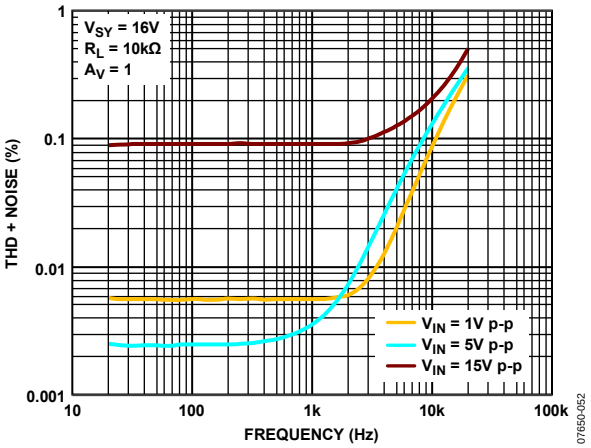

Figure 54. THD + Noise vs. Frequency

APPLICATIONS INFORMATION

RAIL-TO-RAIL INPUT OPERATION

The ADA4665-2 is a unity-gain stable CMOS operational amplifier designed with rail-to-rail input/output swing capability to optimize performance. The rail-to-rail input feature is vital to maintain the wide dynamic input voltage range and to maximize signal swing to both supply rails. For example, the rail-to-rail input feature is extremely useful in buffer applications where the input voltage must cover both the supply rails.

The input stage has two input differential pairs, nMOS and pMOS. When the input common-mode voltage is at the low end of the input voltage range, the pMOS input differential pair is active and amplifies the input signal. As the input common-mode voltage is slowly increased, the pMOS differential pair gradually turns off while the nMOS input differential pair turns on. This transition is inherent to all rail-to-rail input amplifiers that use the dual differential pairs topology. For the ADA4665-2, this transition occurs approximately 1 V away from the positive rail and results in a change in offset voltage due to the different offset voltages of the differential pairs (see Figure 5 and Figure 8).

CURRENT SHUNT SENSOR

Many applications require the sensing of signals near the positive or the negative rails. Current shunt sensors are one such application and are mostly used for feedback control systems. They are also used in a variety of other applications, including power metering, battery fuel gauging, and feedback controls in electrical power steering. In such applications, it is desirable to use a shunt with very low resistance to minimize the series voltage drop. This not only minimizes wasted power, but also allows the measurement of high currents while saving power. The ADA4665-2 provides a low cost solution for implementing current shunt sensors.

Figure 55 shows a low-side current sensing circuit, and Figure 56 shows a high-side current sensing circuit using the ADA4665-2. A typical shunt resistor of 0.1 Ω is used. In these circuits, the difference amplifier amplifies the voltage drop across the shunt resistor by a factor of 100. For true difference amplification, matching of the resistor ratio is very important, where R1/R2 = R3/R4. The rail-to-rail feature of the ADA4665-2 allows the output of the op amp to almost reach 16 V (the power supply of the op amp). This allows the current shunt sensor to sense up to approximately 1.6 A of current.

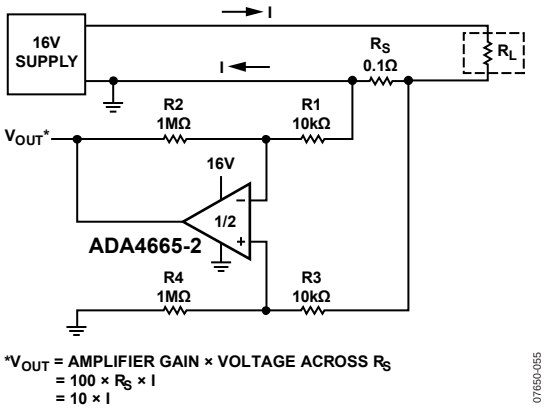

Figure 55. Low-Side Current Sensing Circuit

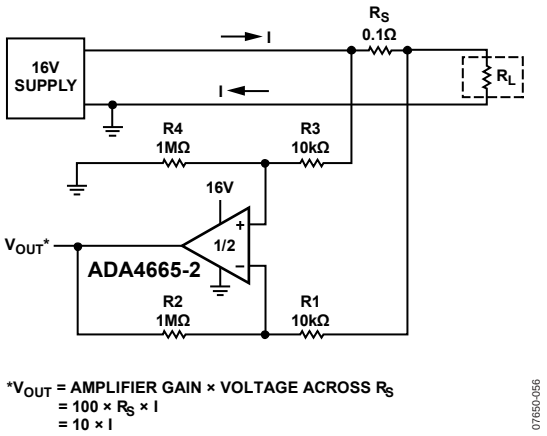

Figure 56. High-Side Current Sensing Circuit

ACTIVE FILTERS

The ADA4665-2 is well suited for active filter designs. An active filter requires an op amp with a unity-gain bandwidth at least 100 times greater than the product of the corner frequency, f_c, and the quality factor, Q. An example of an active filter is the Sallen-Key, one of the most widely used filter topologies. This topology gives the user the flexibility of implementing either a low-pass or a high-pass filter by simply interchanging the resistors and capacitors. To achieve the desired performance, 1% or better component tolerances are usually required.

Figure 57 shows a two-pole low-pass filter. It is configured as a unity-gain filter with cutoff frequency at 10 kHz. Resistor and capacitor values are chosen to give a quality factor, Q, of $1/\sqrt{2}$ for a Butterworth filter, which has maximally flat pass-band frequency response. Figure 58 shows the frequency response of the low-pass Sallen-Key filter. The response falls off at a rate of 40 dB per decade after the cutoff frequency of 10 kHz.

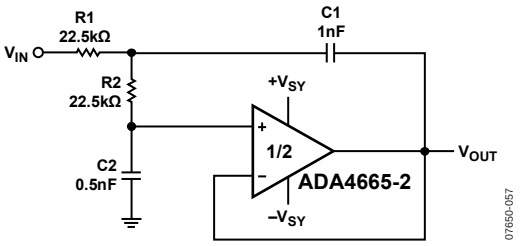

Figure 57. Two-Pole Low-Pass Filter

When R1 = R2 and C1 = 2C2, the values of Q and the cutoff frequency are calculated as follows:

$$Q = \frac{\sqrt{R1\,R2\,C1\,C2}}{C2(R1+R2)}$$

$$f_c = \frac{1}{2\pi\sqrt{R1\,R2\,C1\,C2}}$$

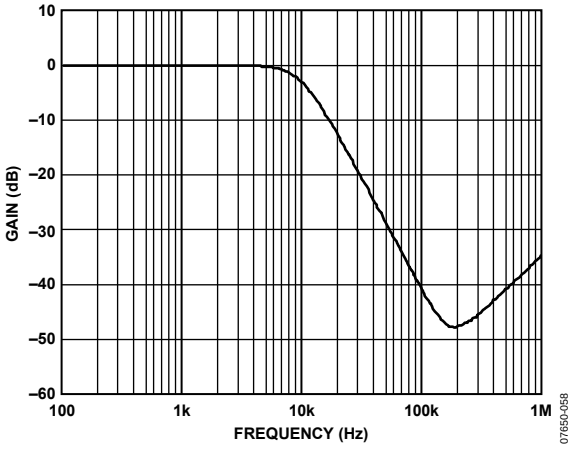

Figure 58. Low-Pass Filter: Gain vs. Frequency

Figure 59 shows a two-pole high-pass filter, with cutoff frequency at 10 kHz and quality factor, Q, of 1/√2.

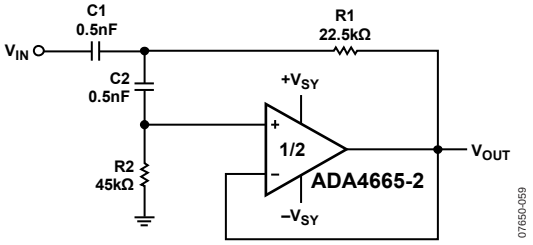

Figure 59. Two-Pole High-Pass Filter

When R2 = 2R1 and C1 = C2, the values of Q and the cutoff frequency are calculated as follows:

$$Q = \frac{\sqrt{R1\,R2\,C1\,C2}}{R1(C1+C2)}$$

$$f_c = \frac{1}{2\pi\sqrt{R1\,R2\,C1\,C2}}$$

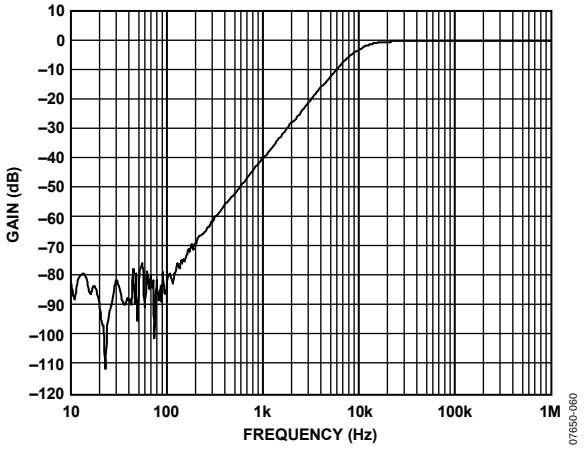

Figure 60. High-Pass Filter: Gain vs. Frequency

OUTLINE DIMENSIONS

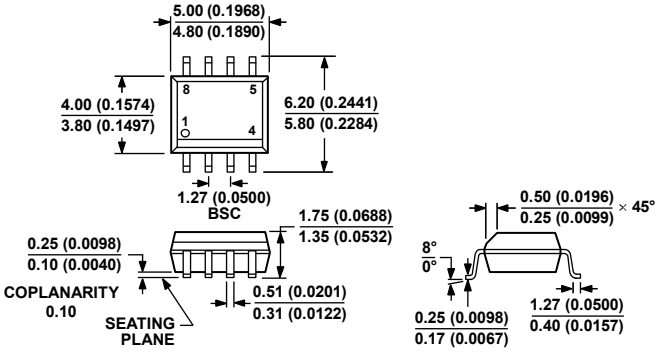

Figure 61. 8-Lead Standard Small Outline Package [SOIC_N]
Narrow Body
(R-8)
Dimensions shown in millimeters and (inches)

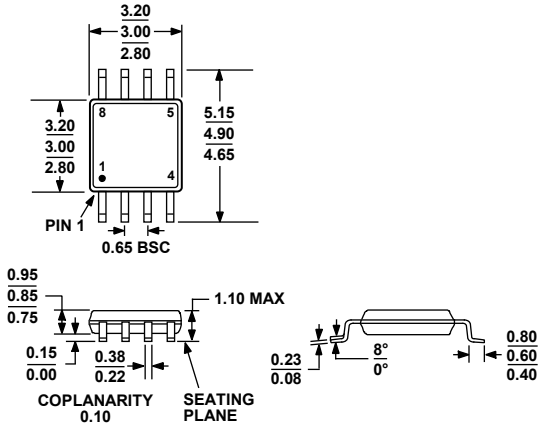

Figure 62. 8-Lead Mini Small Outline Package [MSOP]
(RM-8)
Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Branding
ADA4665-2ARZ[1]	−40°C to +125°C	8-Lead SOIC_N	R-8	
ADA4665-2ARZ-RL[1]	−40°C to +125°C	8-Lead SOIC_N	R-8	
ADA4665-2ARZ-R7[1]	−40°C to +125°C	8-Lead SOIC_N	R-8	
ADA4665-2ARMZ[1]	−40°C to +125°C	8-Lead MSOP	RM-8	A26
ADA4665-2ARMZ-R7[1]	−40°C to +125°C	8-Lead MSOP	RM-8	A26
ADA4665-2ARMZ-RL[1]	−40°C to +125°C	8-Lead MSOP	RM-8	A26

[1] Z = RoHS Compliant Part.

NOTES

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NOTES

D07650-0-1/09(0)

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